Electronic and Optical Properties in Cu-based Materials for Thin-film Solar Cells

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14th-May-2015



What materials am I working on?

Commercial materials:

$$Cu(In,Ga)Se_2$$
 and $Cu_2(Zn,Sn)Se_4$.

• High absorption materials:

$$Cu(Sb,Bi)(S,Se)_2$$
 and $Cu_3(Sb,Bi)(S,Se)_3$.

Noval materials:

$$Cu_2S$$
, SnS , Cu_2SnS_3 and Cu_4SnS_4 .

Motivation

We want to understand Cu-based materials for solar cells.

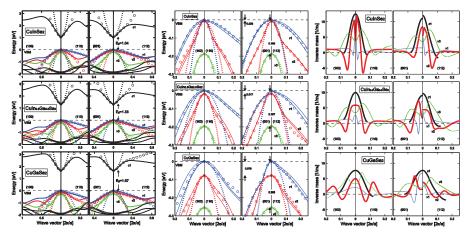
- Why some materials have high or low absorption coefficient?
- How good band-gap can we obtain using theoretical calculation?

Computational methods

- Fundamental methods
 - Density-functional theory (DFT).
 - Kohn-Sham (KS) equation.
- Beyond DFT
 - GW approximation.
 - Heyd-Scuseria-Ernzerhof (HSE) hybrid functional.

Previous results 1: parameterization of band structure

Thin Solid Films **519**, 7503 (2011). Journal of Applied Physics 112, 103708 (2012).

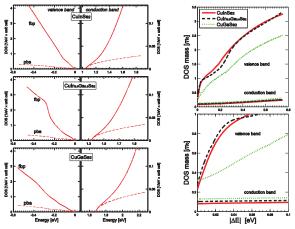


Band structure along four directions. Circles(fbp), Dotted(pba), and solid lines (calculation).

Inverse of electron and hole masses.

Previous results 1: density-of-states (DOS) and DOS mass

Thin Solid Films **519**, 7503 (2011). Journal of Applied Physics **112**, 103708 (2012).



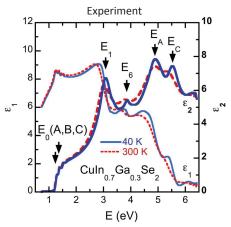
Others:

Fermi level and band-gap with temperature.

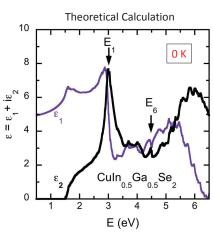
Carrier concentration in intrinsic and p-type $Cu(In, Ga)Se_2$.

Previous results 2: dielectric function for CuIn_{0.5}Ga_{0.5}Se₂

Applied Physics Letters 101, 261903 (2012).



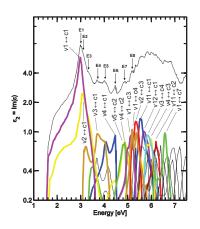
The real (ϵ_1) and imaginary (ϵ_2) part of dielectric function spectra for CuIn $_{0.7}$ Ga $_{0.3}$ Se $_2$ at 40 K (solid lines) and 300 K (dashed lines).



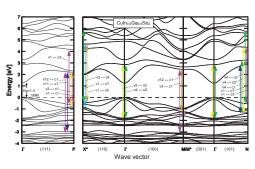
The dielectric function spectra for $CuIn_{0.7}Ga_{0.3}Se_2$ calculated at 0 K.

Previous results 2: analysis of the imaginary part of dielectric function

Applied Physics Letters 101, 261903 (2012).

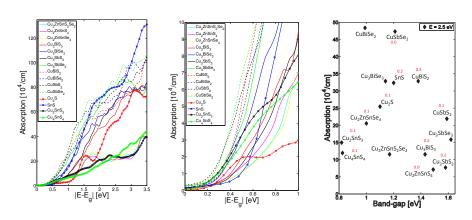


Band-to-band analysis of the contribution to the total ε_2 spectrum. The vertical axis is in the log scale.



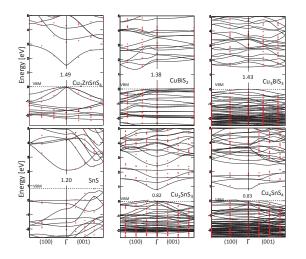
The calculated electronic band structure of $\text{CuIn}_{0.5}\text{Ga}_{0.5}\text{Se}_2$ where the CPs are identified along the main symmetry directions.

Current results: absorption and band-gap in Cu-based materials



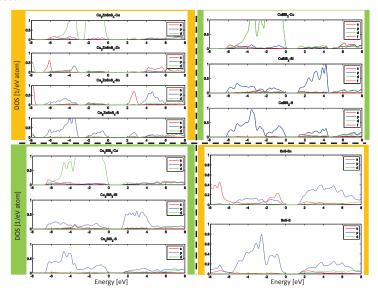
HSE: Cu_2SnS_3 and Cu_4SnS_4 , GW: others. CSHIFT=0.03.

Current results: band structure in Cu-based materials

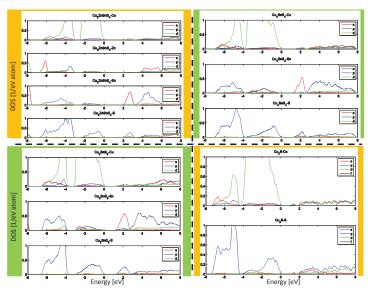


 $Circles(HSE: Cu_2SnS_3 \ and \ Cu_4SnS_4, \ GW: \ others), \ solid \ lines(PBE).$

Current results: density-of-states in Cu-based materials

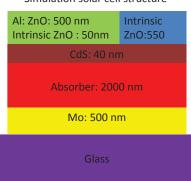


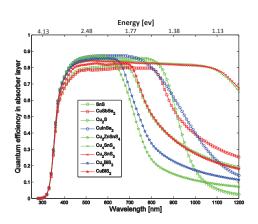
Current results: density-of-states in Cu-based materials



add a model figure





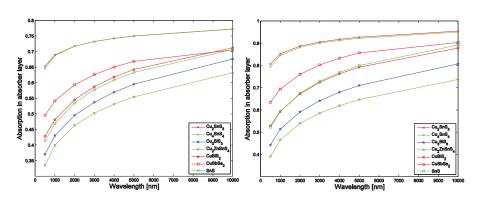


Optical efficiency in each layer:

$$A(d_i) = \frac{\int I(\lambda)QE(\lambda, d_i)d\lambda}{\int I(\lambda)d\lambda}$$
 (1)

$$A'(d_i) = \frac{\int I(\lambda)QE(\lambda, d_i)d\lambda}{\int I(\lambda)QE(\lambda, d_i = \infty)d\lambda}$$
 (2)

Here, $I(\lambda)$ is the spectral power density of the AM1.5 solar spectrum with wavelength λ . QE(λ, d_i) is the quantum efficiency in the corresponding layer with thickness d_i .



Summary

- Previous work:
 - Eergy bands are non-parabolic even very close to the Γ -point, and the effective masses are **k**-dependency.
 - The dielectric function calculated by our theoretical method shows a good agreement with the result of experiment.
- Current work:
 - ..
 - ...

Acknowledgements

- I would like to express my sincere appreciation to my supervisor Prof. Clas Persson for his academic encouragement and professional guidance.
- I would like to thank all the group colleagues in Stockholm and Oslo for helpful research discussions and chatting. I would like to thank all other people at the Department of Material Sciences and Engineering at KTH for creating a nice working atmosphere.
- The China Scholarship Council, the Swedish Energy Agency, the Swedish Research Council, Stiftelsen Axel Hultgrens fond, Olle Erikssons stiftelse for materialteknik, and KTH Computational Science and Engineering Centre (KCSE) are acknowledged for financial support.